IP4303CX4 (/P)

Dual back-to-back diode array with ESD protection to IEC61000-4-2, level4

15 May 2009

Product data sheet

1. Product profile

1.1 General description

IP4303CX4 (/P) is a diode array, which is designed to provide protection to downstream components from Electrostatic Discharge (ESD) voltages as high as ± 15 kV contact, far exceeding the IEC61000-4-2, level4.

IP4303CX4 (/P) is fabricated by using monolithic silicon semiconductor technology and integrates four pseudo back-to-back diodes in a single Wafer-Level chip-scale package. These features make IP4303CX4 (/P) ideal for use in applications requiring component miniaturization, such as mobile phone handsets, cordless telephones and personal digital devices. For mechanically demanding applications the option /P as IP4303CX4/P is offering improved mechanical stability by using advanced solder balls.

1.2 Features

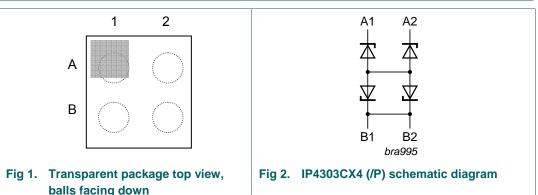
- Pb-free, RoHS compliant and free of Halogen and Antimony (dark green compliant)
- 2 back-to-back diodes with common ground
- Back to back diodes to provide downstream ESD protection up to ±15 kV (contact)
- Wafer-Level chip-scale package with 0.4 mm pitch only

1.3 Applications

General purpose ESD-protection in mobile appliances such as but not limited to:

- Cellular and PCS mobile handsets
- Wireless data (WAN/LAN) systems

2. Pinning Information





3. Limiting values

Table 1. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage Range		-12.0	+12.0	V
ESD	Electrostatic Discharge, all pins	IEC 61000-4-2, Level 4, Contact Discharge Air Discharge	-8(-15) ¹ -15	+8(+15) ¹ +15	kV kV
T _{stg}	storage temperature range		-55	+150	°C
T _{pk}	Peak solder reflow temperature	10 seconds max.		+260	°C
T _{amb}	Ambient operating temperature		-30	+85	°C

4. Electrical Characteristics

Table 2. Electrical characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR+)}$	Diode breakdown voltage, positive voltages	I _{test} = 1 mA	14	16.5	-	V
$V_{(BR-)}$	Diode breakdown voltage, negative voltages	I _{test} = 1 mA	-	-16.5	-14	V
I _{Ikg+}	Diode reverse leakage current, per diode pair	V = +5 V	-	-	100	nA
I _{Ikg-}	Diode reverse leakage current, per diode pair	V = -5 V	-	-	100	nA
C _d	Diode capacitance value Pin A to ground (Pin B)	V = 0 V; f = 1 MHz	-	-	15	pF

Device is tested with 1000 pulses of ±15kV contact discharges each, according the IEC61000-4-2 model and far exceeds the specified level 4 (8kV contact discharge)

5. Design/Assembly Recommendations

5.1 PCB Design Guidelines

For the optimum performance, a Non-Solder Mask PCB design (NSMD), also known as a copperdefined design, incorporating laser-drilled micro-vias connecting the ground pads to a buried ground-plane layer is recommended. This results in the lowest possible ground inductance and provides the best high frequency and ESD performance. For this case, the following are the recommended PCB design parameters:

PCB pad size: 0.20 mm diameter
 Micro-Via diameter: 0.1 mm (0.004")
 Solder Mask opening: 0.37 mm diameter

Copper thickness: 20-40 µmCopper finish: AuNiPCB material: FR4

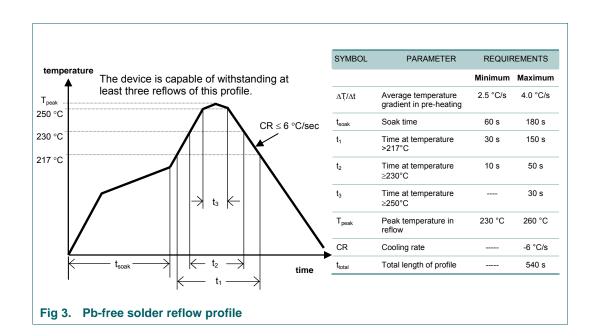
5.2 PCB Assembly Guidelines for Pb-free soldering

The following are recommendations for the assembly of this device:

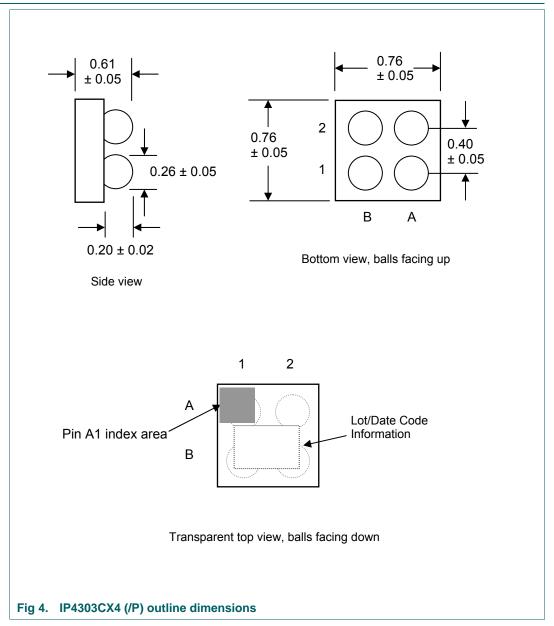
■ Solder Screen Aperture size: 0.33 mm diameter
■ Solder Screen thickness: 100 µm (0.004")

Solder Paste: Pb-free: Sn Ag(3-4) Cu(0.5-0.9)

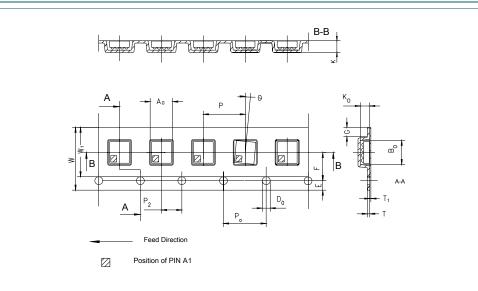
Solder/Flux ratio: 50 / 50Solder Reflow Profile: see below



6. Package outline



7. Tape & Reel information



ITEM		SYMBOL SPECIFICATIONS		NOTE	
			DIMENSION	TOLERANCE	
OVERALL DIMENSIONS	TAPE WIDTH	W	8.00	±0.1	
	THICKNESS	K	1.20	MAX	
	DISTANCE	G	0.75	MIN	
SPROCKET HOLES	DIAMETER	D ₀	1.50	+0.1/-0.0	CUM. PITCH ERROR
	DISTANCE	Е	1.75	±0.1	±0.2 / 10 PITCHES
	PITCH	P ₀	4.00	±0.1	
DISTANCE BETWEEN	LENGTH DIRECTION	P ₂	2.00	±0.05	
CENTRE LINES	WIDTH DIRECTION	F	3.50	±0.05	
COMPARTMENTS	LENGTH	A ₀	0.85	±0.05	
	WIDTH	B ₀	0.85	±0.05	
	DEPTH	K ₀	0.70	±0.05	
	PITCH	Р	4.00	±0.1	
DEVICE	OUTLINE	IP4303CX4 (/P)			
	ROTATION	Θ	20°	MAX	
CARRIER TAPE	FILM THICKNESS	Т	0.25	±0.07	CARBON LOADED
ANTISTATIC	BEND		0.25	±0.07	POLYSTYRENE 100% RECYCLABLE
COVER TAPE	WIDTH	W ₁	5.75	MAX	
	FILM THICKNESS	T ₁	0.1	MAX	
BENDING RAD	IN WINDING DIRECTION	R	30	MIN	

Fig 5. IP4303CX4 (/P) Tape & Reel information

8. Legal information

8.1 Data sheet status

Document status ^{[1], [2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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